

BYT03-400

FAST RECOVERY RECTIFIER DIODE

MAJOR PRODUCTS CHARACTERISTICS

I F(AV)	3 A
V _{RRM}	400 V
t _{rr}	25 ns
V _F (max)	1.4 V

FEATURES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

DESCRIPTION

Free wheeling diode in converters and motor control circuits.

Rectifiers in S.M.P.S.





Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	192 TA	400	V
V _{RSM}	Non repetitive peak reverse voltage	All De	400	V
I _{FRM}	Repetive peak forward current	60	Α	
I _{F (AV)}	Average forward current*	3	Α	
I _{FSM}	Surge non repetitive forward current	60	A	
Р	Power dissipation *	Ta = 65°C	4.2	W
T _{stg}	Storage temperature range	- 40 to + 150	°C	
Tj	Maximum operating junction temperatu	re	+ 150	

^{*} On infinite heatsink with 10mm lead lengh.



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THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th (j - a)}	Junction-ambient*	20	°C/W

^{*} On infinite heatsink with 10mm lead lengh.

STATIC ELECTRICAL CHARACTERISTICS

Synbol	Test	Min.	Тур.	Max.	Unit	
I _R	T _j = 25C	$V_R = V_{RRM}$			20	μА
	T _j = 100C				0.5	mA
V _F	T _j = 25C	I _F = 3A			1.5	V
	T _j = 100C				1.4	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Тур.	Max.	Unit
t _{rr}	$T_j = 25C$	$I_F = 1A$ $di_F/dt = -15A/\mu s$ $V_R = 30V$			55	ns
		$I_F = 0.5A$ $I_R = 1 A$ $I_{rr} = 0.25A$			25	

TURN-OFF SWITCHING CHARACTERISTICS - Without series inductance

Symbol	Test	Min.	Тур.	Max.	Unit	
t _{IRM}	di _F /dt = - 50A/μs	$V_{CC} = 200 \text{ V}$ $I_F = 3A$ $I_D \le 0.05 \mu H$ $I_I = 100 ^{\circ} C$		35	50	ns
I _{RM}	di _F /dt = -50A/μs	$L_p \le 0.05 \mu H$ $T_j = 100 ^{\circ} C$		1.5	2	Α

To evaluate the conduction losse use the following equations : $V_F = 1.1 + 0.050~I_F$ $P = 1.1~x~I_{F(AV)} + 0.050~I_F^2_{(RMS)}$

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Fig. 1: Maximum average power dissipation versus average forward current.

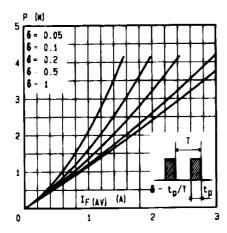


Fig.3: Thermal resistance versus lead length.

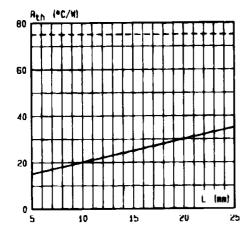


Fig. 4: Transient thermal impedance junction ambient for mounting n° 2 versus pulse duration (L = 10 mm).

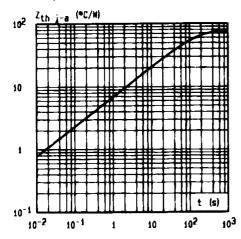
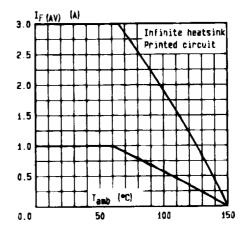


Fig. 2: Average forward current versus ambient temperature.





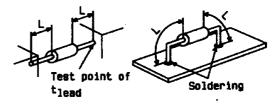


Fig. 5: Peak forward current versus peak forward voltage drop (maximum values).

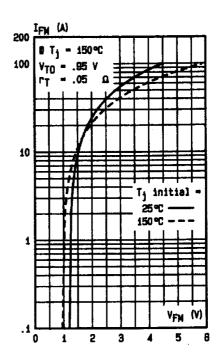


Fig. 7: Recovery time versus dI_F/dt.

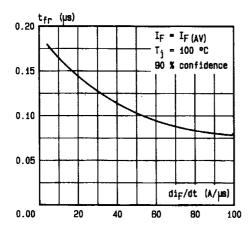


Fig. 9: Peak reverse current versus dI_F/dt .

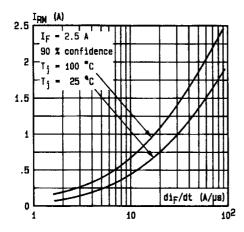


Fig. 11: Dynamic parameters versus junction temperature.

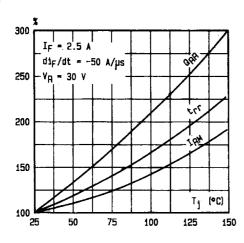


Fig. 8: Peak forward voltage versus dl_F/dt.

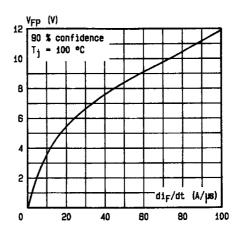


Fig. 10: Recovery charge versus dl_F/dt (typical values).

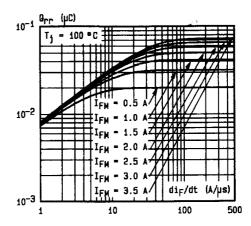
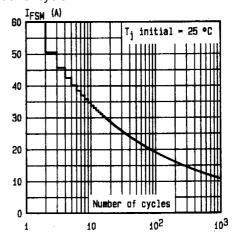
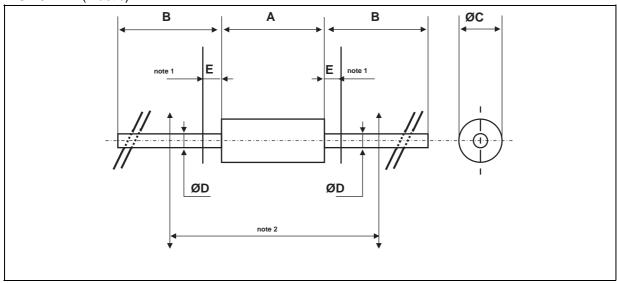


Fig. 12: Non repetitive surge peak current versus number of cycle.



PACKAGE MECHANICAL DATA

DO-201AD (Plastic)



		DIMEN	SIONS		
REF.	Millimeters Inches		hes	NOTES	
	Min.	Max.	Min.	Max.	
Α		9.50		0.374	1 - The lead diameter Ø D is not controlled over zone E
В	25.40		1.000		2 - The minimum axial length within which the device may be
ØC		5.30		0.209	placed with its leads bent at right angles is 0.59"(15 mm)
Ø D		1.30		0.051	
Е		1.25		0.049	

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